
MR27V6402D

Preliminary

4,194,304-Word x 16-Bit or 8,388,608-Word x 8-Bit One Time PROM

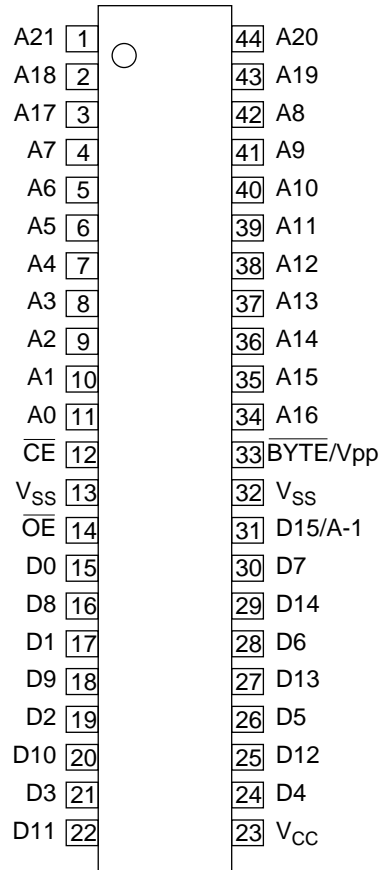
DESCRIPTION

The MR27V6402D is a 64Mbit electrically Programmable Read-Only Memory whose configuration can be electrically switched between 4,194,304 word x 16bit and 8,388,608 word x 8bit. The MR27V6402D operates on a single +3V-3.3V power supply and is TTL compatible. Since the MR27V6402D operates asynchronously, external clocks are not required, making this device easy-to-use. The MR27V6402D is suitable as large-capacity fixed memory for microcomputers and data terminals. It is manufactured using a CMOS double silicon gate technology and is offered in 44-pin SOP package.

FEATURES

- 4,194,304 word x 16bit / 8,388,608 word x 8bit electrically switchable configuration
- Single +3V-3.3V power supply
- Access time 150ns access time (Vcc=+3V)
 120ns access time (Vcc=+3.3V)
- Input / Output TTL compatible
- Three-state output
- Package
 44-pin plastic SOP (SOP44-P-600-1.27-K)

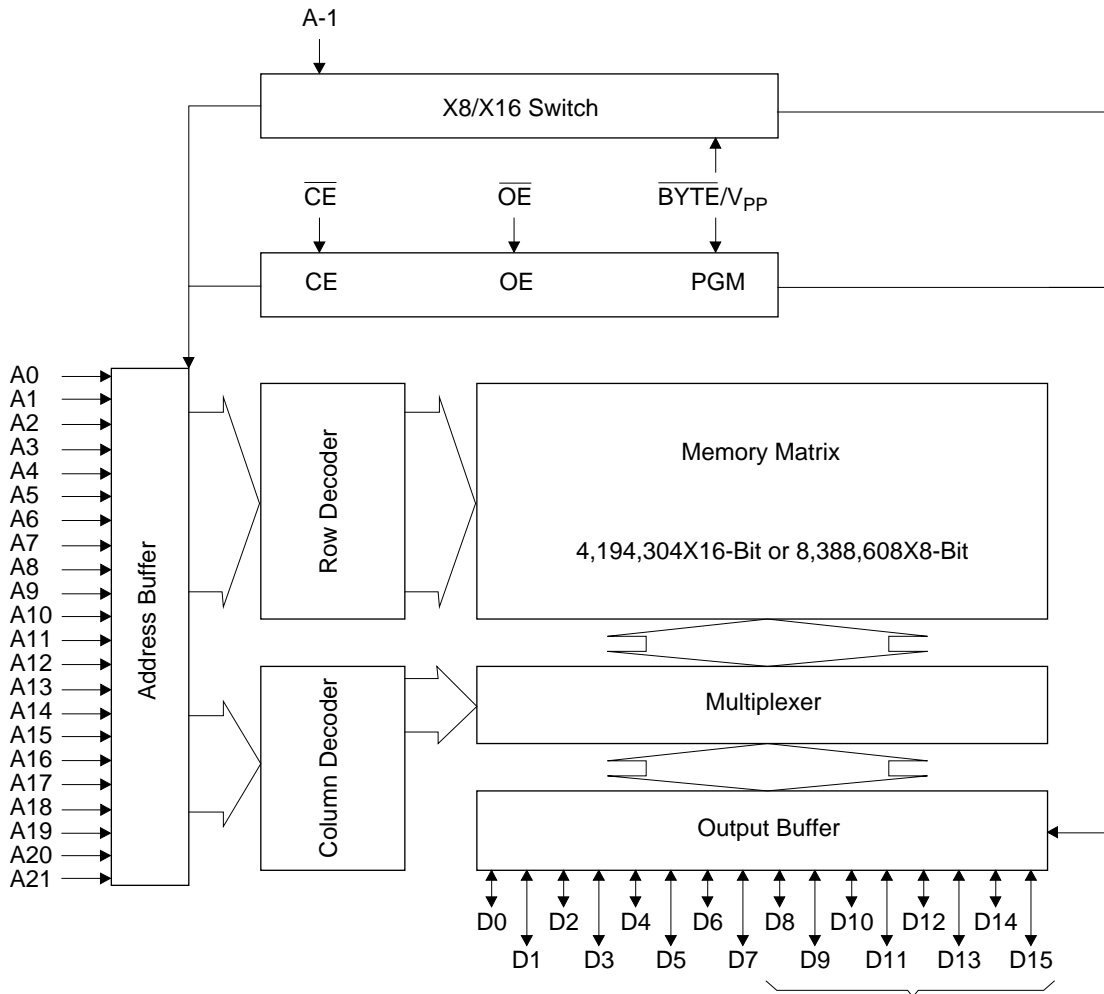
PIN CONFIGURATION (TOP VIEW)



44-pin SOP

PIN NAMES	FUNCTIONS
D15/A-1	Data output / Address input
A0-A21	Address input
D0-D14	Data output
$\overline{\text{CE}}$	Chip enable
$\overline{\text{OE}}$	Output enable
V _{CC}	Power supply voltage
V _{SS}	GND
$\overline{\text{BYTE/V}}_{\text{PP}}$	Mode switch / Program power supply voltage

BLOCK DIAGRAM



In 8-bit output mode, these pins are three-stated and pin D15 functions as the A-1 address pin.

FUNCTION TABLE

MODE	$\overline{\text{CE}}$	$\overline{\text{OE}}$	$\overline{\text{BYTE}}/V_{\text{PP}}$	V_{CC}	D0 - D7	D8 - D14	D15/A-1
READ (16-Bit)	L	L	H	3.0V to 3.3V	D_{OUT}		
READ (8-Bit)	L	L	L		D_{OUT}	Hi-Z	L/H
OUTPUT DISABLE	L	H	H		Hi-Z		*
			L		Hi-Z		*
STAND-BY	H	*	H	Hi-Z		*	
			L	Hi-Z		*	
PROGRAM	L	H	9.75V	4.0V	D_{IN}		
PROGRAM INHIBIT	H	H			Hi-Z		
PROGRAM VERIFY	H	L			D_{OUT}		

*: Don't Care

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Value	Unit
Operating temperature under bias	T_{opr}	-	0 to 70	°C
Storage temperature	T_{stg}		-55 to 125	°C
Input voltage	V_I	relative to V_{SS}	-0.5 to $V_{CC} + 0.5$	V
Output voltage	V_O		-0.5 to $V_{CC} + 0.5$	V
Power supply voltage	V_{CC}		-0.5 to 5	V
Program power supply voltage	V_{PP}		-0.5 to 11.5	V
Power dissipation per package	P_D	-	1.0	W

RECOMMENDED OPERATING CONDITIONS

(Ta=0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
V_{CC} power supply voltage	V_{CC}	$V_{CC}=2.7V-3.6V$	2.7	-	3.6	V
V_{PP} power supply voltage	V_{PP}		-0.5	-	$V_{CC}+0.5$	V
Input "H" level	V_{IH}		2.2	-	$V_{CC}+0.5$	V
Input "L" level	V_{IL}		-0.5	-	0.6	V

Voltage is relative to V_{SS}

ELECTRICAL CHARACTERISTICS (Read operation)

DC Characteristics 1

($V_{CC}=3V\pm 0.3V$, $T_a=0$ to $70^\circ C$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I_{LI}	$V_I=0$ to V_{CC}	-	-	10	μA
Output leakage current	I_{LO}	$V_O=0$ to V_{CC}	-	-	10	μA
V_{CC} power supply current (Standby)	I_{CCSC}	$\overline{CE}=V_{CC}$	-	-	50	μA
	I_{CCST}	$\overline{CE}=V_{IH}$	-	-	1	mA
V_{CC} power supply current (Read)	I_{CCA}	$\overline{CE}=V_{IL}$, $\overline{OE}=V_{IH}$ $t_c=150ns$	-	-	45	mA
V_{PP} power supply current	I_{PP}	$V_{PP}=V_{CC}$	-	-	10	μA
Input "H" level	V_{IH}	-	2.2	-	$V_{CC}+0.5$	V
Input "L" level	V_{IL}	-	-0.5	-	0.6	V
Output "H" level	V_{OH2}	$I_{OH}=-200\mu A$	$V_{CC}-0.4$	-	-	V
Output "L" level	V_{OL2}	$I_{OL}=1mA$	-	-	0.4	V

Voltage is relative to V_{SS}

DC Characteristics 2

($V_{CC}=3.3V\pm 0.3V$, $T_a=0$ to $70^\circ C$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I_{LI}	$V_I=0$ to V_{CC}	-	-	10	μA
Output leakage current	I_{LO}	$V_O=0$ to V_{CC}	-	-	10	μA
V_{CC} power supply current (Standby)	I_{CCSC}	$\overline{CE}=V_{CC}$	-	-	50	μA
	I_{CCST}	$\overline{CE}=V_{IH}$	-	-	1	mA
V_{CC} power supply current (Read)	I_{CCA}	$\overline{CE}=V_{IL}$, $\overline{OE}=V_{IH}$ $t_c=120ns$	-	-	50	mA
V_{PP} power supply current	I_{PP}	$V_{PP}=V_{CC}$	-	-	10	μA
Input "H" level	V_{IH}	-	2.2	-	$V_{CC}+0.5$	V
Input "L" level	V_{IL}	-	-0.5	-	0.6	V
Output "H" level	V_{OH2}	$I_{OH}=-200\mu A$	$V_{CC}-0.4$	-	-	V
Output "L" level	V_{OL2}	$I_{OL}=1mA$	-	-	0.4	V

Voltage is relative to V_{SS}

AC Characteristics 1(V_{CC}=3V±0.3V, T_a=0 to 70°C)

Parameter	Symbol	Condition	Min.	Max.	Unit
Address cycle time	T _C	-	150	-	ns
Address access time	T _{ACC}	$\overline{CE}=\overline{OE}=V_{IL}$	-	150	ns
\overline{CE} access time	T _{CE}	$\overline{OE}=V_{IL}$	-	150	ns
\overline{OE} access time	T _{OE}	$\overline{CE}=V_{IL}$	-	60	ns
Output disable time	T _{CHZ}	$\overline{OE}=V_{IL}$	0	50	ns
	T _{OHZ}	$\overline{CE}=V_{IL}$	0	45	ns
Output hold time	T _{OH}	$\overline{CE}=\overline{OE}=V_{IL}$	0	-	ns

Measurement conditions

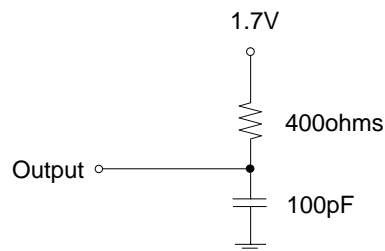
Input signal level	-----	0V/3V
Input timing reference level	-----	0.8V/2.0V
Output load	-----	100pF
Output timing reference level	-----	0.8V/2.0V

AC Characteristics 2(V_{CC}=3.3V±0.3V, T_a=0 to 70°C)

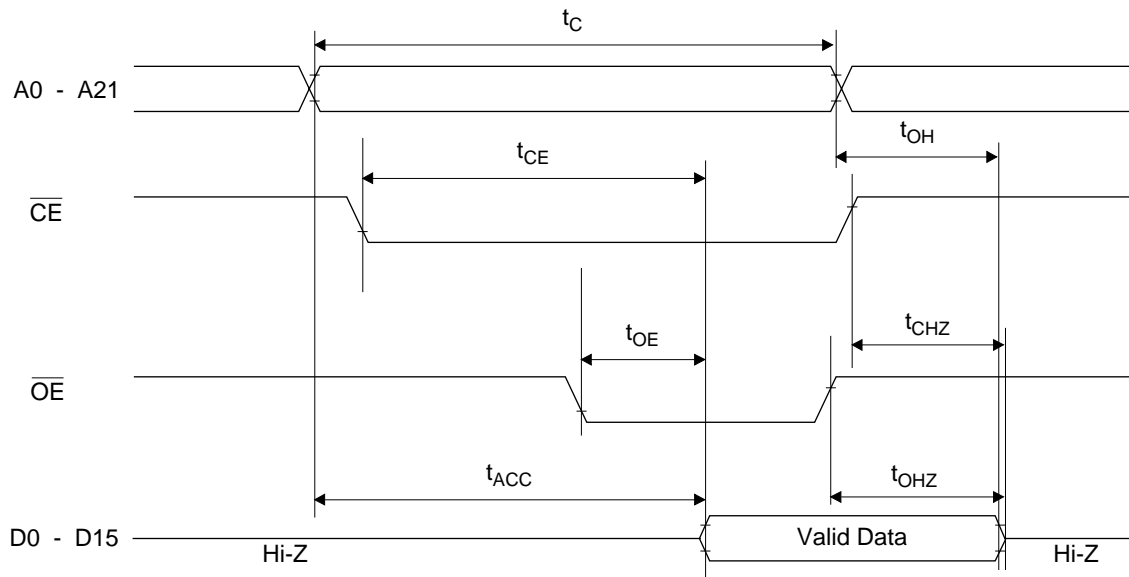
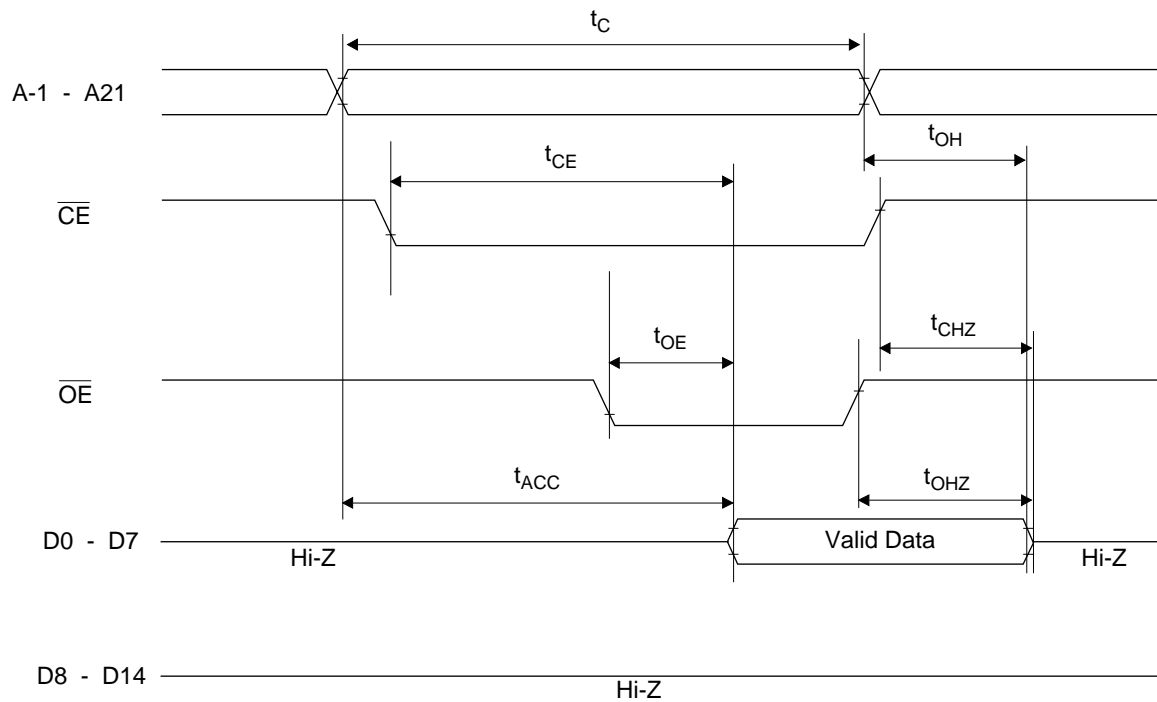
Parameter	Symbol	Condition	Min.	Max.	Unit
Address cycle time	T _C	-	120	-	ns
Address access time	T _{ACC}	$\overline{CE}=\overline{OE}=V_{IL}$	-	120	ns
\overline{CE} access time	T _{CE}	$\overline{OE}=V_{IL}$	-	120	ns
\overline{OE} access time	T _{OE}	$\overline{CE}=V_{IL}$	-	50	ns
Output disable time	T _{CHZ}	$\overline{OE}=V_{IL}$	0	40	ns
	T _{OHZ}	$\overline{CE}=V_{IL}$	0	35	ns
Output hold time	T _{OH}	$\overline{CE}=\overline{OE}=V_{IL}$	0	-	ns

Measurement conditions

Input signal level	-----	0V/3V
Input timing reference level	-----	0.8V/2.0V
Output load	-----	100pF
Output timing reference level	-----	0.8V/2.0V



TIMING CHART (READ CYCLE)

16-Bit Read Mode ($\overline{\text{BYTE}}=\text{V}_{\text{IH}}$)8-Bit Read Mode ($\overline{\text{BYTE}}=\text{V}_{\text{IL}}$)

ELECTRICAL CHARACTERISTICS (Programming operation)

DC Characteristics

(Ta=25°C±5°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I _{LI}	V _I =V _{CC} +0.5V	-	-	10	μA
V _{PP} power supply current (Program)	I _{PP2}	$\overline{CE}=V_{IL}$	-	-	50	mA
V _{CC} power supply current	I _{CC}	-	-	-	50	mA
Input "H" level	V _{IH}	-	3.0	-	V _{CC} +0.5	V
Input "L" level	V _{IL}	-	-0.5	-	0.8	V
Output "H" level	V _{OH}	I _{OH} =-400μA	2.4	-	-	V
Output "L" level	V _{OL}	I _{OL} =2.1mA	-	-	0.45	V
Program voltage	V _{PP}	-	9.5	9.75	10.0	V
V _{CC} power supply voltage	V _{CC}	-	3.9	4.0	4.1	V

Voltage is relative to V_{SS}

AC Characteristics

(V_{CC}=4.0V±0.1V, V_{pp}=9.75V±0.25V, Ta=25°C±5°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Address set-up time	T _{AS}	-	100	-	-	ns
\overline{OE} set-up time	T _{OES}	-	2	-	-	μs
Data set-up time	T _{DS}	-	100	-	-	ns
Address hold time	T _{AH}	-	2	-	-	μs
Data hold time	T _{DH}	-	100	-	-	ns
Output float delay from \overline{OE}	T _{OHZ}	-	0	-	100	ns
V _{PP} voltage set-up time	T _{VS}	-	2	-	-	μs
Program pulse width	T _{PW}	-	9	10	11	μs
Data valid from \overline{OE}	T _{OE}	-	-	-	100	ns
Address hold from \overline{OE} high	T _{AHO}	-	0	-	-	ns

Pin Check Function

Pin Check Function is to check contact between each device-pin and each socket-lead with EPROM programmer.

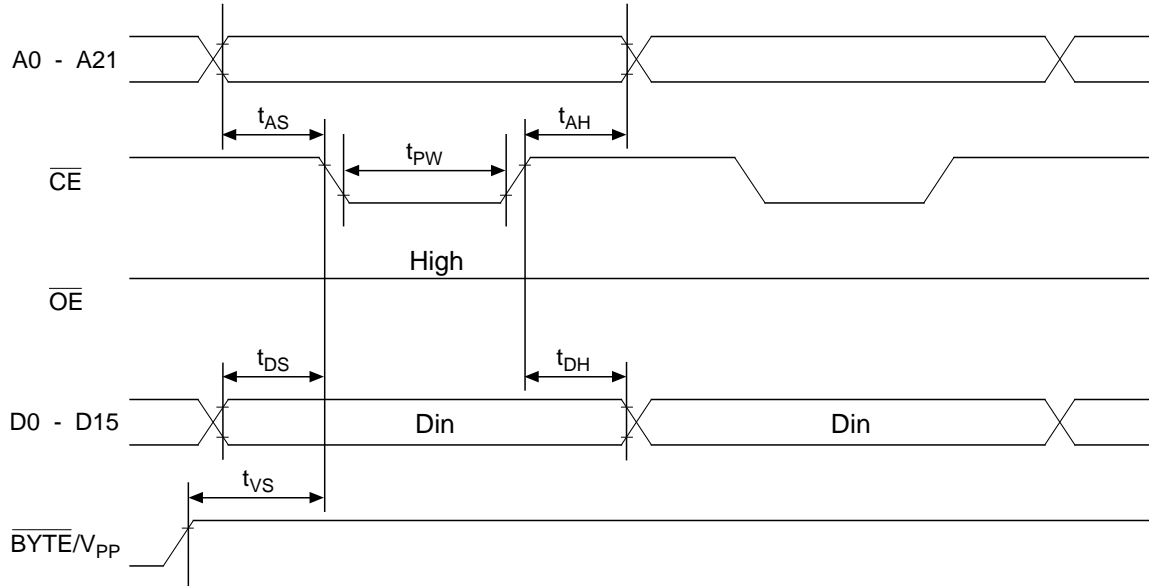
Setting up address as the following condition call the preprogrammed codes on device outputs.

(V_{CC}=3.3V±0.3V, $\overline{CE}=\overline{OE}=V_{IL}$, $\overline{BYTE}/V_{pp}=V_{IH}$, Ta=25°C±5°C)

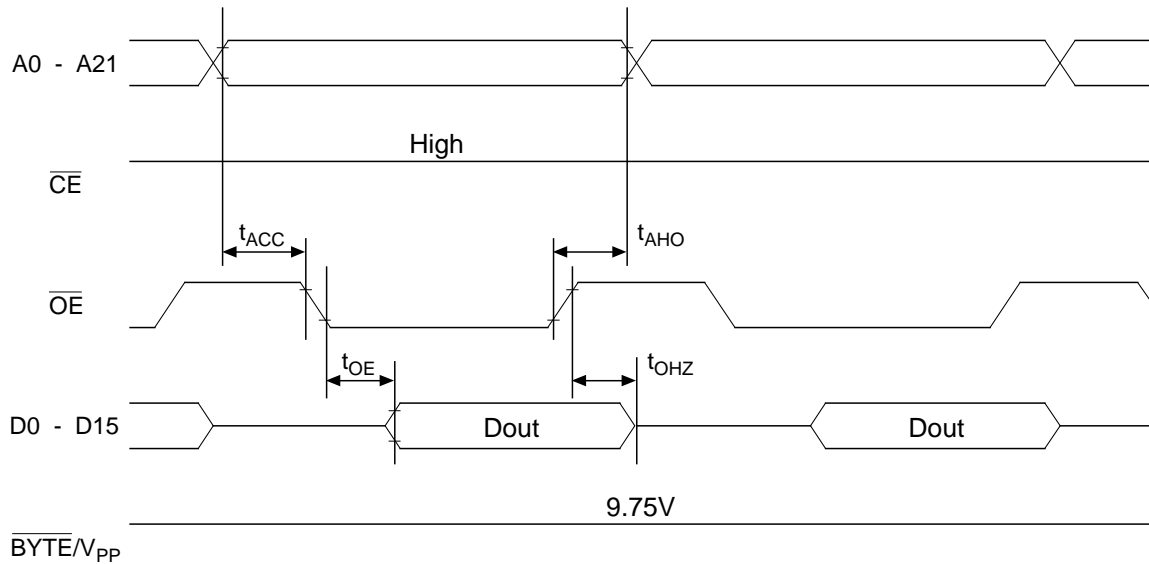
A0	A1	A2	A3	A4	A5	A6	A7	A8	A9	A10	A11	A12	A13	A14	A15	A16	A17	A18	A19	A20	A21	DATA
0	1	0	1	0	1	0	1	0	VH*	0	1	0	1	0	1	0	0	1	1	0	0	FF00
1	0	1	0	1	0	1	0	1	VH*	1	0	1	0	1	0	1	1	0	0	1	1	00FF
Other conditions																					FFFF	

* :VH=8V±0.25V

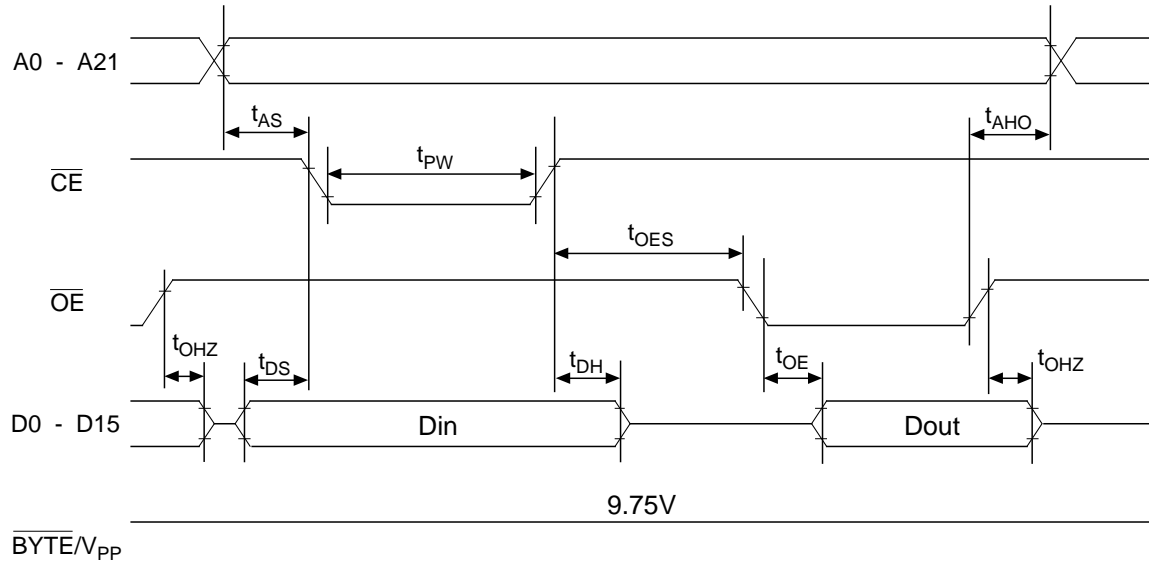
Consecutive Programming Waveforms



Consecutive Program Verify Waveforms



Program and Program Verify Cycle Waveforms



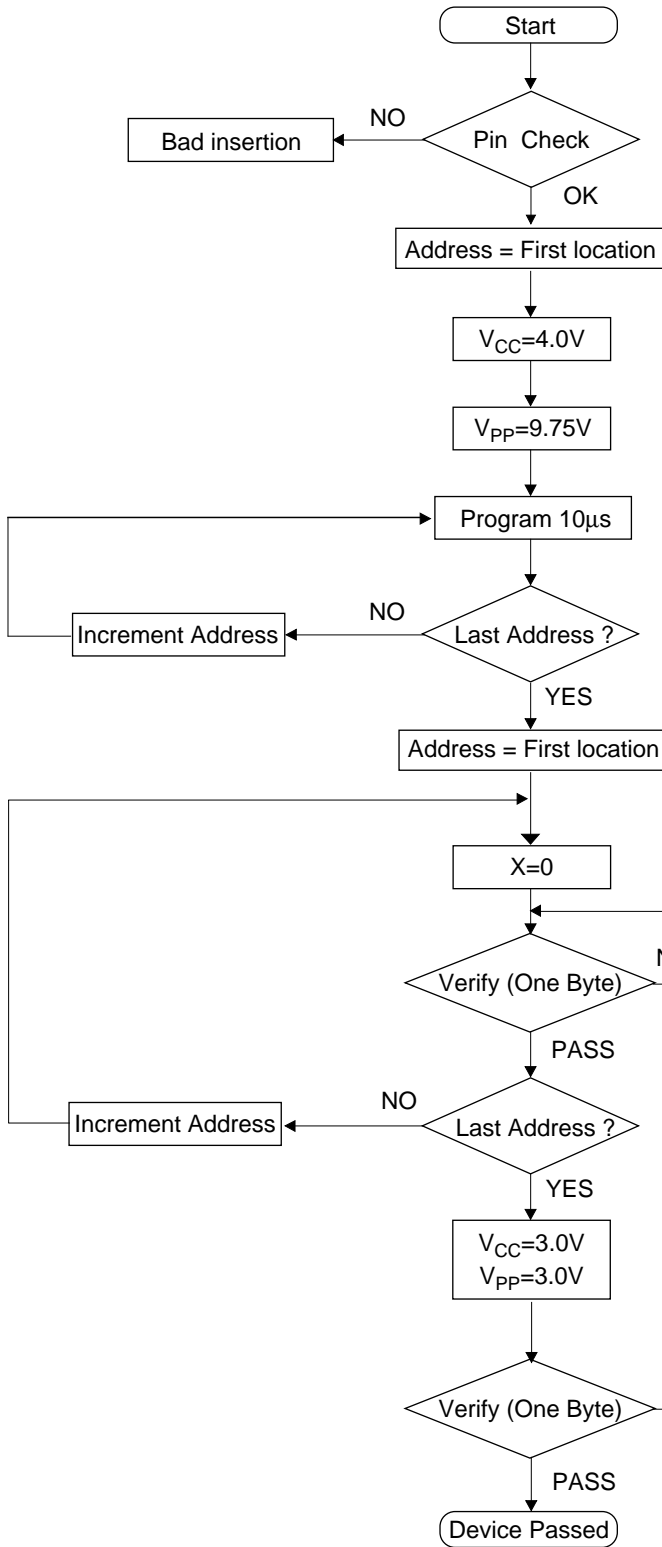
PIN Capacitance

($V_{CC}=3.3V$, $T_a=25^\circ C$, $f=1MHz$)

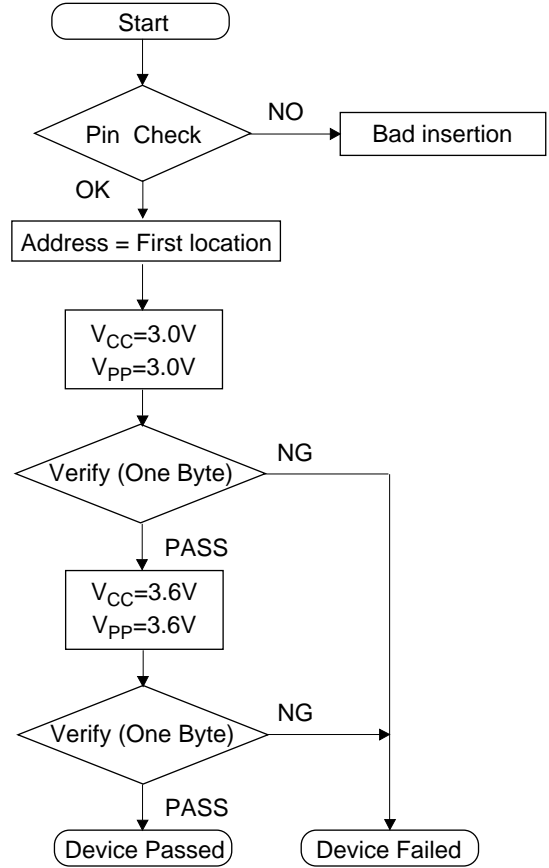
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input	C_{IN1}	$V_I=0V$	-	-	12	pF
\overline{BYTE}/V_{PP}	C_{IN2}		-	-	120	
Output	C_{OUT}	$V_O=0V$	-	-	15	

Programming / Verify Flow Chart

Programming



Verify



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OKI

People To People Technology

ADDRESSES & SEMICONDUCTOR WEB SITES

OKI Electric Industry Co., Ltd.,

Device Business Group,
10-3, Shibaura, 4-chome,
Minato-ku, Tokyo 108, Japan,
Tel.: +81-(0)3-5445-6327,
Fax.: +81-(0)3-5445-6328,
<http://www.oki.co.jp/semi/>

OKI Semiconductor Group,

785 North Mary Avenue,
Sunnyvale, CA 94086, U.S.A.,
Tel.: +1-408-720-1900,
Fax.: +1-408-720-1918,
<http://www.okisemi.com/>

OKI Electric Europe GmbH,

Head Office Europe,
Hellersbergstrasse 2,
D-41460 Neuss, Germany,
Tel: +49-2131-15960,
Fax: +49-2131-103539,
<http://www.oki-europe.de/>

OKI Electronics (Hong Kong) Ltd.,

Suite 1901-1&19, Tower 3,
China Hong Kong City,
33 Canton Road, Tsimshatsui,
Kowloon, Hong Kong,
Tel.: +852-2-736-2336,
Fax.: +852-2-736-2395

OKI Semiconductor (Asia) Pte. Ltd.,

78 Shenton Way 09-01,
Singapore 0207,
Tel.: +65-221-3722,
Fax.: +65-323-5376

OKI Semiconductor (Asia) Pte. Ltd.,

Taipei Branch,
7th Fl. No.260, Tun Hwa North Road,
Taipei, Taiwan, R.O.C.,
Sumitomo-Flysun Building,
Tel.: +886-2-2719-2561,
Fax.: +886-2-2715-2892
<http://www.oki.net.tw/>

For further information, please contact: